

# MC74VHC393

## Dual 4-Bit Binary Ripple Counter

The MC74VHC393 is an advanced high speed CMOS dual 4-bit binary ripple counter fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

This device consists of two independent 4-bit binary ripple counters with parallel outputs from each counter stage. A +256 counter can be obtained by cascading the two binary counters.

Internal flip-flops are triggered by high-to-low transitions of the clock input. Reset for the counters is asynchronous and active-high. State changes of the Q outputs do not occur simultaneously because of internal ripple delays. Therefore, decoded output signals are subject to decoding spikes and should not be used as clocks or as strobes except when gated with the Clock of the VHC393.

The inputs tolerate voltages up to 7V, allowing the interface of 5V systems to 3V systems.

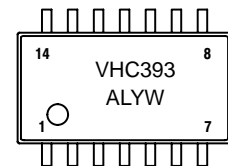
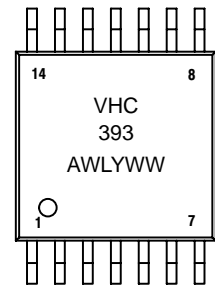
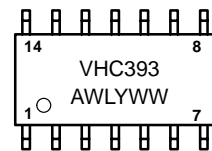
- High Speed:  $f_{max} = 170\text{MHz}$  (Typ) at  $V_{CC} = 5\text{V}$
- Low Power Dissipation:  $I_{CC} = 4\mu\text{A}$  (Max) at  $T_A = 25^\circ\text{C}$
- High Noise Immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC}$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Designed for 2V to 5.5V Operating Range
- Low Noise:  $V_{OLP} = 0.8\text{V}$  (Max)
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300mA
- ESD Performance: HBM > 2000V; Machine Model > 200V
- Chip Complexity: 236 FETs or 59 Equivalent Gates



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### MARKING DIAGRAMS



A = Assembly Location  
L, WL = Wafer Lot  
Y = Year  
W, WW = Work Week

### ORDERING INFORMATION

Device	Package	Shipping
MC74VHC393D	SOIC-14	55 Units/Rail
MC74VHC393DR2	SOIC-14	1000 Units/Reel
MC74VHC393DT	TSSOP-14	96 Units/Rail
MC74VHC393DTR2	TSSOP-14	2500 Units/Reel
MC74VHC393M	SOIC EIAJ-14	50 Units/Rail
MC74VHC393MEL	SOIC EIAJ-14	2000 Units/Reel

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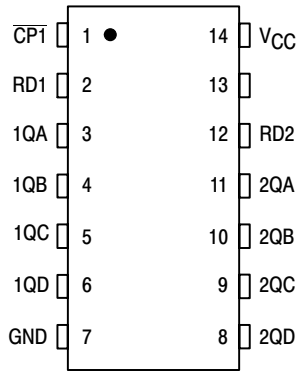


Figure 1. Pin Assignment

## FUNCTION TABLE

Inputs		Outputs
Clock	Reset	
X	H	L
H	L	No Change
L	L	No Change
↑	L	No Change
↓	L	Next State

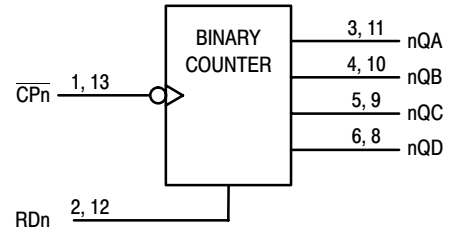


Figure 2. Logic Diagram

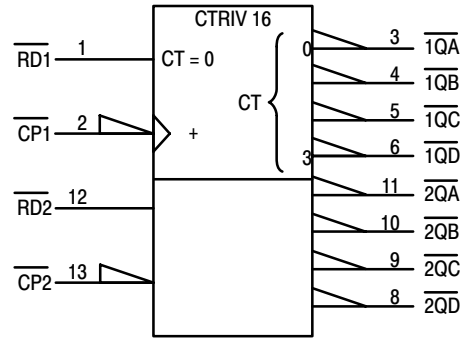


Figure 3. IEC Logic Symbol

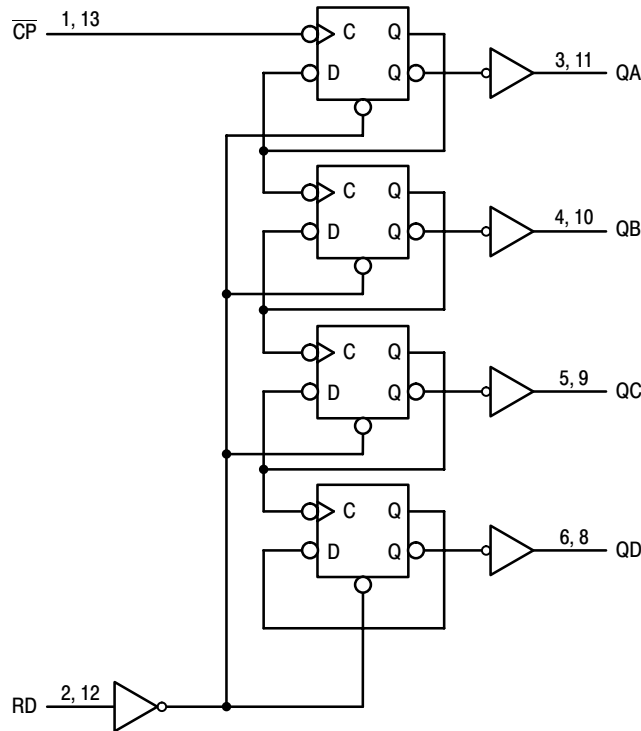


Figure 4. Expanded Logic Diagram

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## MAXIMUM RATINGS\*

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage	- 0.5 to + 7.0	V
V <sub>IN</sub>	DC Input Voltage	- 0.5 to + 7.0	V
V <sub>OUT</sub>	DC Output Voltage	- 0.5 to V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input Diode Current	- 20	mA
I <sub>OK</sub>	Output Diode Current	± 20	mA
I <sub>OUT</sub>	DC Output Current, per Pin	± 25	mA
I <sub>CC</sub>	DC Supply Current, V <sub>CC</sub> and GND Pins	± 75	mA
P <sub>D</sub>	Power Dissipation in Still Air, SOIC Packages† TSSOP Package†	500 450	mW
T <sub>stg</sub>	Storage Temperature	- 65 to + 150	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V<sub>in</sub> and V<sub>out</sub> should be constrained to the range GND ≤ (V<sub>in</sub> or V<sub>out</sub>) ≤ V<sub>CC</sub>. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V<sub>CC</sub>). Unused outputs must be left open.

\* Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied.

† Derating — SOIC Packages: - 7 mW/°C from 65° to 125°C  
TSSOP Package: - 6.1 mW/°C from 65° to 125°C

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage	2.0	5.5	V
V <sub>IN</sub>	DC Input Voltage	0	5.5	V
V <sub>OUT</sub>	DC Output Voltage	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature	- 55	+ 125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time V <sub>CC</sub> = 3.3V V <sub>CC</sub> = 5.0V	0 0	100 20	ns/V

The θ<sub>JA</sub> of the package is equal to 1/Derating. Higher junction temperatures may affect the expected lifetime of the device per the table and figure below.

## DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

Junction Temperature °C	Time, Hours	Time, Years
80	1,032,200	117.8
90	419,300	47.9
100	178,700	20.4
110	79,600	9.4
120	37,000	4.2
130	17,800	2.0
140	8,900	1.0

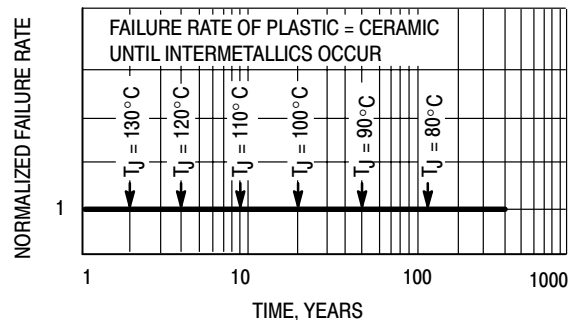


Figure 5. Failure Rate vs. Time Junction Temperature

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## DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			T <sub>A</sub> = ≤ 85°C		T <sub>A</sub> = ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
V <sub>IH</sub>	Minimum High-Level Input Voltage		2.0	1.5			1.5		1.5		V
			3.0	2.1			2.1		2.1		
			4.5	3.15			3.15		3.15		
			5.5	3.85			3.85		3.85		
V <sub>IL</sub>	Maximum Low-Level Input Voltage		2.0			0.5		0.5		0.5	V
			3.0			0.9		0.9		0.9	
			4.5			1.35		1.35		1.35	
			5.5			1.65		1.65		1.65	
V <sub>OH</sub>	Minimum High-Level Output Voltage V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>OH</sub> = -50 μA	2.0	1.9	2.0		1.9		1.9		V
			3.0	2.9	3.0		2.9		2.9		
		4.5	4.4	4.5		4.4		4.4		4.4	
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>OH</sub> = -4 mA I <sub>OH</sub> = -8 mA	3.0	2.58			2.48		2.34		
4.5	3.94				3.80		3.66				
V <sub>OL</sub>	Maximum Low-Level Output Voltage V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>OL</sub> = 50 μA	2.0		0.0	0.1		0.1		0.1	V
			3.0		0.0	0.1		0.1		0.1	
		4.5		0.0	0.1		0.1		0.1		
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>OL</sub> = 4 mA I <sub>OL</sub> = 8 mA	3.0			0.36		0.44		0.52	
4.5				0.36		0.44		0.52			
I <sub>IN</sub>	Maximum Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	0 to 5.5			± 0.1		± 1.0		μA	
I <sub>CC</sub>	Maximum Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5			4.0		40.0		μA	

## AC ELECTRICAL CHARACTERISTICS (Input t<sub>r</sub> = t<sub>f</sub> = 3.0ns)

Symbol	Parameter	Test Conditions	T <sub>A</sub> = 25°C			T <sub>A</sub> = ≤ 85°C		T <sub>A</sub> = ≤ 125°C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
f <sub>max</sub>	Maximum Clock Frequency (50% Duty Cycle)	V <sub>CC</sub> = 3.3 ± 0.3 V C <sub>L</sub> = 15pF C <sub>L</sub> = 50pF	75 45	120 65		65 35		65 35		MHz
		V <sub>CC</sub> = 5.0 ± 0.5 V C <sub>L</sub> = 15pF C <sub>L</sub> = 50pF	125 85	170 115		105 75		105 75		
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, CP to QA	V <sub>CC</sub> = 3.3 ± 0.3 V C <sub>L</sub> = 15pF C <sub>L</sub> = 50pF		8.6 11.1	13.2 16.7	1.0 1.0	15.5 19.0	1.0 1.0	15.5 19.0	ns
		V <sub>CC</sub> = 5.0 ± 0.5 V C <sub>L</sub> = 15pF C <sub>L</sub> = 50pF		5.8 7.3	8.5 10.5	1.0 1.0	10.0 12.0	1.0 1.0	10.0 12.0	
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, CP to QB	V <sub>CC</sub> = 3.3 ± 0.3 V C <sub>L</sub> = 15pF C <sub>L</sub> = 50pF		10.2 12.7	15.8 19.3	1.0 1.0	18.5 22.0	1.0 1.0	18.5 22.0	ns
		V <sub>CC</sub> = 5.0 ± 0.5 V C <sub>L</sub> = 15pF C <sub>L</sub> = 50pF		6.8 8.3	9.8 11.8	1.0 1.0	11.5 13.5	1.0 1.0	11.5 13.5	
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, CP to QC	V <sub>CC</sub> = 3.3 ± 0.3 V C <sub>L</sub> = 15pF C <sub>L</sub> = 50pF		11.7 14.2	18.0 21.5	1.0 1.0	21.0 24.5	1.0 1.0	21.0 24.5	ns
		V <sub>CC</sub> = 5.0 ± 0.5 V C <sub>L</sub> = 15pF C <sub>L</sub> = 50pF		7.7 9.2	11.2 13.2	1.0 1.0	13.0 15.0	1.0 1.0	13.0 15.0	
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, CP to QD	V <sub>CC</sub> = 3.3 ± 0.3 V C <sub>L</sub> = 15pF C <sub>L</sub> = 50pF		13.0 15.5	19.7 23.2	1.0 1.0	23.0 26.5	1.0 1.0	23.0 26.5	ns
		V <sub>CC</sub> = 5.0 ± 0.5 V C <sub>L</sub> = 15pF C <sub>L</sub> = 50pF		8.5 10.0	12.5 14.5	1.0 1.0	14.5 16.5	1.0 1.0	14.5 16.5	

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## AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0\text{ns}$ )

Symbol	Parameter	Test Conditions	$T_A = 25^\circ\text{C}$			$T_A = \leq 85^\circ\text{C}$		$T_A = \leq 125^\circ\text{C}$		Unit
			Min	Typ	Max	Min	Max	Min	Max	
$t_{PHL}$	Maximum Propagation Delay, RD to QN	$V_{CC} = 3.3 \pm 0.3\text{ V}$ $C_L = 15\text{pF}$ $C_L = 50\text{pF}$		7.9	12.3	1.0	14.5	1.0	14.5	ns
				10.4	15.8	1.0	18.0	1.0	18.0	
$t_{OSLH}$ , $t_{OSHL}$	Output to Output Skew	$V_{CC} = 3.3 \pm 0.3\text{ V}$ $C_L = 50\text{pF}$ (Note 1.)			1.5		1.5		1.5	pF
					1.0		1.0		1.0	pF
$C_{IN}$	Maximum Input Capacitance			4	10		10		10	pF

		Typical @ $25^\circ\text{C}$ , $V_{CC} = 5.0\text{V}$	Unit
$C_{PD}$	Power Dissipation Capacitance (Note 2.)	23	pF

- Parameter guaranteed by design.  $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$ ,  $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$ .
- $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC(OPR)} = C_{PD} \cdot V_{CC} \cdot f_{in} + I_{CC}$ .  $C_{PD}$  is used to determine the no-load dynamic power consumption;  $P_D = C_{PD} \cdot V_{CC}^2 \cdot f_{in} + I_{CC} \cdot V_{CC}$ .

## NOISE CHARACTERISTICS (Input $t_r = t_f = 3.0\text{ns}$ , $C_L = 50\text{pF}$ , $V_{CC} = 5.0\text{V}$ )

Symbol	Parameter	$T_A = 25^\circ\text{C}$		Unit
		Typ	Max	
$V_{OLP}$	Quiet Output Maximum Dynamic $V_{OL}$	0.5	0.8	V
$V_{OLV}$	Quiet Output Minimum Dynamic $V_{OL}$	-0.5	-0.8	V
$V_{IHD}$	Minimum High Level Dynamic Input Voltage		3.5	V
$V_{ILD}$	Maximum Low Level Dynamic Input Voltage		1.5	V

## TIMING REQUIREMENTS (Input $t_r = t_f = 3.0\text{ns}$ )

Symbol	Parameter	Test Conditions	$T_A = 25^\circ\text{C}$		$T_A = \leq 85^\circ\text{C}$	$T_A = \leq 125^\circ\text{C}$	Unit
			Typ	Limit	Limit	Limit	
$t_w$	Minimum Pulse Width, $\overline{CP}$	$V_{CC} = 3.3 \pm 0.3\text{ V}$ $V_{CC} = 5.0 \pm 0.5\text{ V}$		5.0 5.0	5.0 5.0	5.0 5.0	ns
$t_w$	Minimum Pulse Width, RD	$V_{CC} = 3.3 \pm 0.3\text{ V}$ $V_{CC} = 5.0 \pm 0.5\text{ V}$		5.0 5.0	5.0 5.0	5.0 5.0	ns
$t_{rec}$	Minimum Recovery Time, RD to $\overline{CP}$	$V_{CC} = 3.3 \pm 0.3\text{ V}$ $V_{CC} = 5.0 \pm 0.5\text{ V}$		5.0 4.0	5.0 4.0	5.0 4.0	ns
$t_r, t_f$	Minimum Input Rise and Fall Times	$V_{CC} = 3.3 \pm 0.3\text{ V}$ $V_{CC} = 5.0 \pm 0.5\text{ V}$		330 100	330 100	330 100	ns

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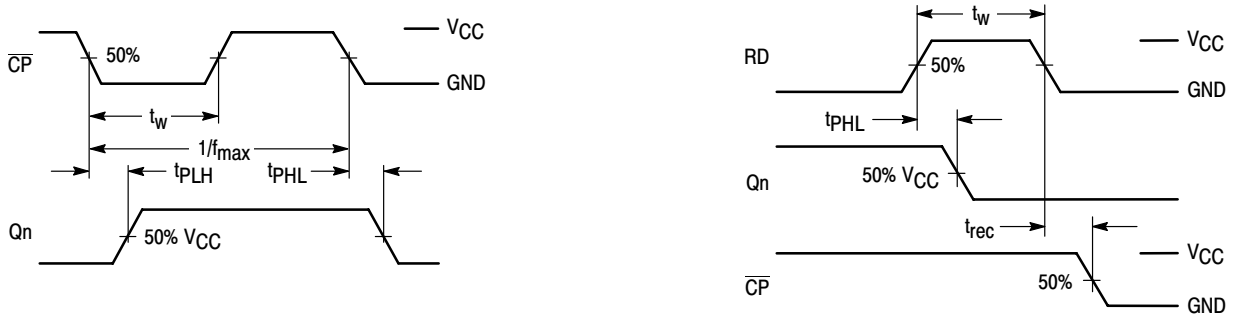
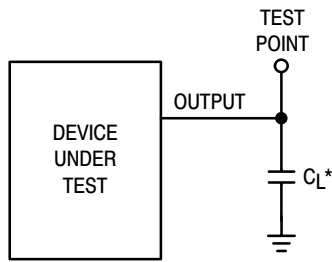


Figure 6. Switching Waveforms



\*Includes all probe and jig capacitance

Figure 7. Test Circuit

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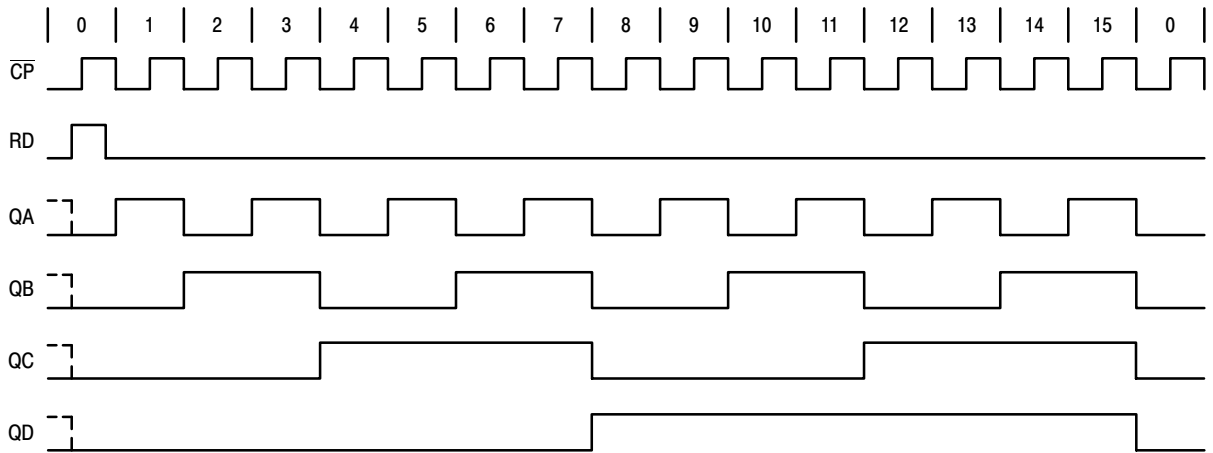


Figure 8. Timing Diagram

## COUNT SEQUENCE

Count	Outputs			
	QD	QC	QB	QA
0	L	L	L	L
1	L	L	L	H
2	L	L	H	L
3	L	L	H	H
4	L	H	L	L
5	L	H	L	H
6	L	H	H	L
7	L	H	H	H
8	H	L	L	L
9	H	L	L	H
10	H	L	H	L
11	H	L	H	H
12	H	H	L	L
13	H	H	L	H
14	H	H	H	L
15	H	H	H	H